

PRODUCT DATA SHEET



To learn more about JGSEMI, please visit our website at



Please note: Please check the JINGAO Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.jg-semi.cn. Please email any questions regarding the system integration to JINGAO_questions@jgsemi.com.



CD1005-B0130L

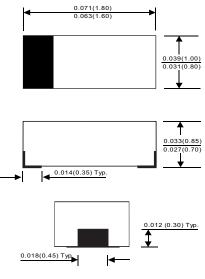
SMD Schottky Barrier Diode

Features

- Low forward Voltage
- Designed for mounting on small surface.
- Extremely thin/leadless package.
- Majority carrier conduction.

Mechanical data

- Case: SOD-523F (1608) Standard package, molded plastic.
- Terminals: Gold plated, solderable per MIL-STD-750, method 2026.
- Polarity: Indicated by cathode band.
- Mounting position: Any. Weight: 0.003 gram (approximately).



Dimensions in inches and (millimeter)

0603(1608)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Repetitive peak reverse voltage		Vrrm			35	V
Reverse voltage		Vr			30	V
Average forward rectified current		lo			200	mA
Forward current , surge peak	8.3 ms singlehalf sine-wave superimposed on rate load (JEDEC method)	lfsm			1	A
Storage temperature		Тѕтс	-40		+125	°c
Junction temperature		Тj	-40		+125	°C

Maximum Rating (at TA = 25°C unless otherwise noted)

Electrical Characteristics (at TA = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Мах	Unit
Forward voltage	I F = 200 mA	Vf			0.6	V
Reverse current	VR = 10 V	lr			1	uA

Ver.1.0



CD1005-B0130L

RATING AND CHARACTERISTIC CURVES

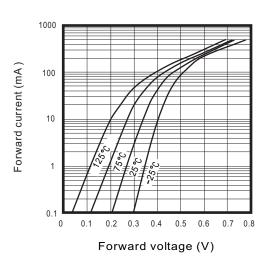


Fig. 3 - Capacitance between terminals characteristics

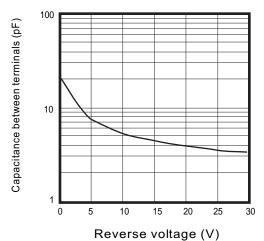


Fig. 1 - Forward characteristics

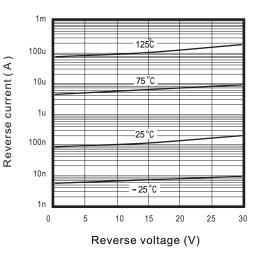
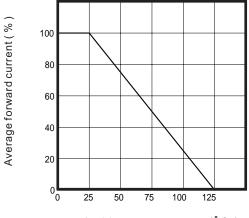


Fig. 2 - Reverse characteristics

Fig. 4 - Current derating curve



Ambient temperature (°C)

Ver.1.0





Attention

1, Any and all JGSEMI products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, orother applic ations whose failure can be reasonably expected to result in serious physical or material damage. Consult with your JGSEMI representative nearest you before using any JGSEMI products described or contained herein in such applications.

2,JGSEMI assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all JGSEMI products described or contained herein.

3, Specifications of any and all JGSEMI products described or contained herein stipulate the performance, characteri stics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To ver ify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate an d test devices mounted in the customer's products or equipment.

4, In the event that any or all JGSEMI products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported wit hout obtaining the export license from the authorities concerned in accordance with the above law.

5, No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanic al, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the pr ior written permission of JGSEMI Semiconductor CO., LTD.

6, Any and all information described or contained herein are subject to change without notice due to product technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the JGSEMI produ ct that you Intend to use.

Ver.1.0